

N-CANNEL MOS FIELD EFFECT POWER TRANSISTOR

2SK703

DESCRIPTION The 2SK703 is N-Channel MOS Field Effect Power Transistor designed for solenoid, motor and lamp driver.

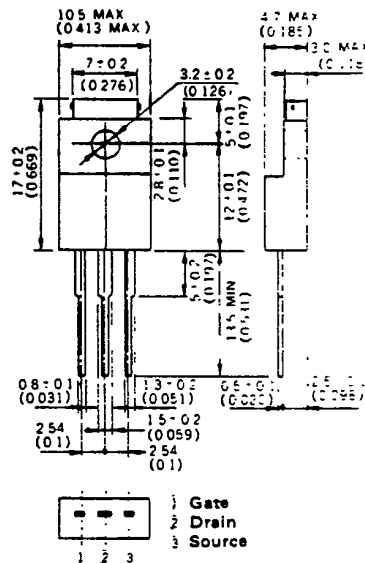
- FEATURES**
- 4 V Gate Drive – Logic level –
 - Low $R_{DS(on)}$
 - No Second Breakdown

ABSOLUTE MAXIMUM RATINGS

Maximum Temperatures	
Storage Temperature	-55 to +150 °C
Junction Temperature	150 °C Maximum
Maximum Power Dissipations	
Total Power Dissipation	2.0 W
Total Power Dissipation ($T_c = 25 °C$)	35 W
Maximum Voltages and Currents ($T_a = 25 °C$)	
V_{DSS} Drain to Source Voltage	100 V
V_{GSS} Gate to Source Voltage	±20 V
$I_{D(DC)}$ Drain Current (DC)	±5 A
$I_{D(pulse)}$ Drain Current (pulse)*	±20 A

* $PW \leq 300 \mu s$, Duty Cycle $\leq 10 \%$

PACKAGE DIMENSIONS
in millimeters (inches)



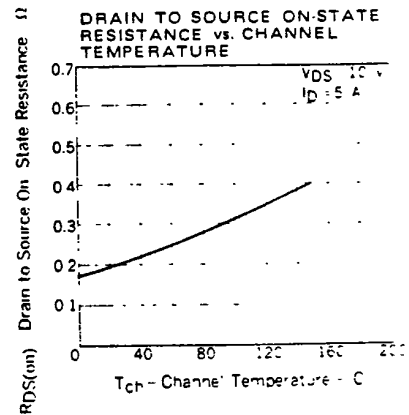
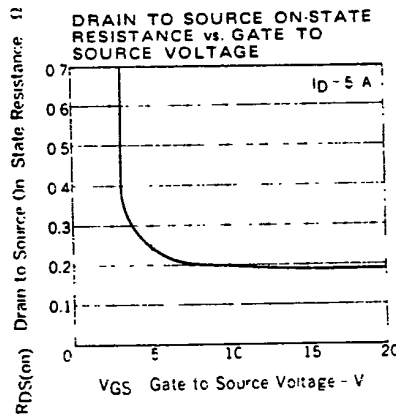
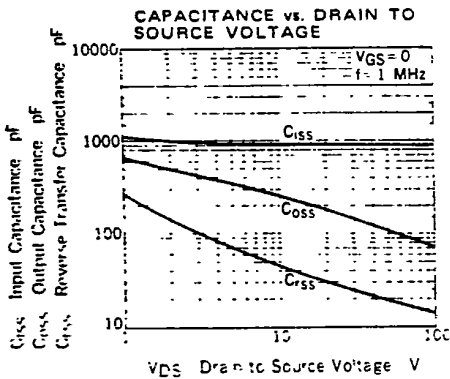
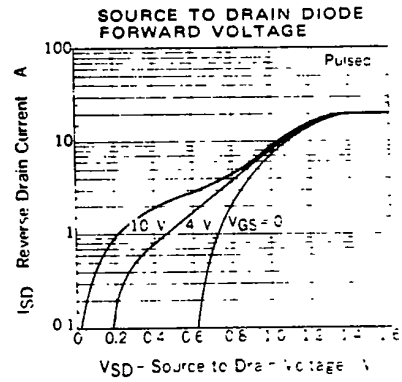
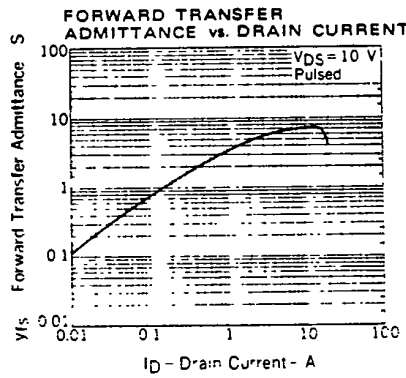
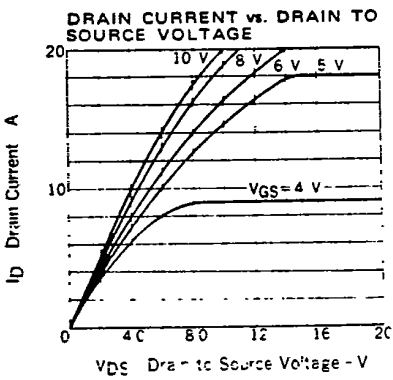
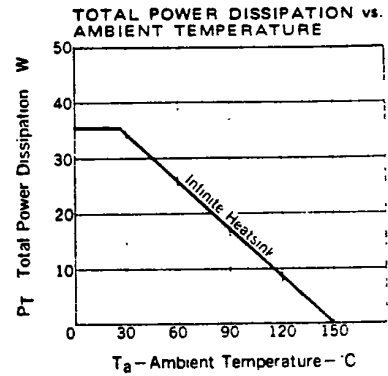
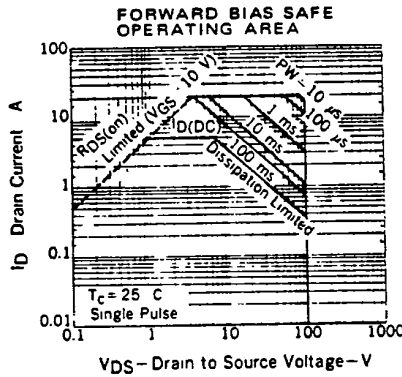
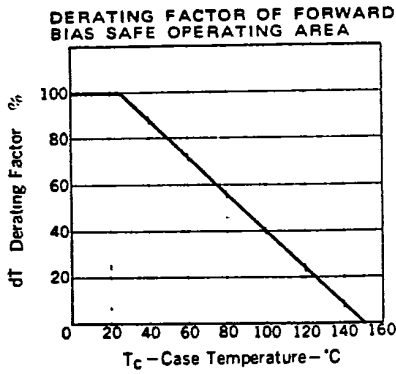
ELECTRICAL CHARACTERISTICS ($T_a = 25 °C$)

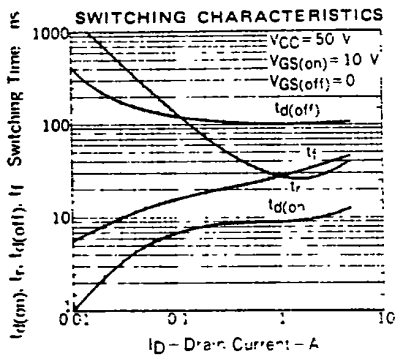
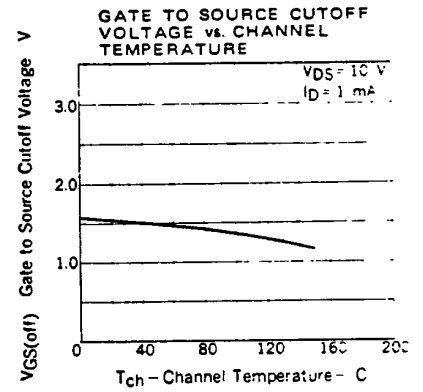
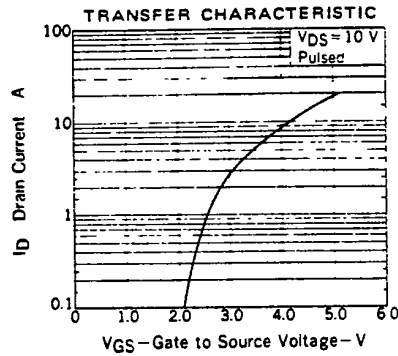
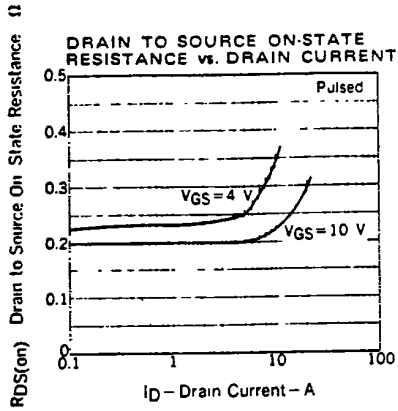
SYMBOL	CHARACTERISTIC	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
$R_{DS(on)}$	Drain to Source On-State Resistance		0.20	0.45	Ω	$V_{GS} = 10 V, I_D = 5 A$
$R_{DS(on)}$	Drain to Source On-State Resistance		0.25	0.50	Ω	$V_{GS} = 4 V, I_D = 5 A$
$V_{GS(off)}$	Gate to Source Cutoff Voltage	1.0		2.5	V	$V_{DS} = 10 V, I_D = 1 mA$
$ y_{fs} $	Forward Transfer Admittance	4.0			S	$V_{DS} = 10 V, I_D = 3 A$
I_{DSS}	Drain Leakage Current			10	μA	$V_{DS} = 100 V, V_{GS} = 0$
I_{GSS}	Gate to Source Leakage Current			±100	nA	$V_{GS} = \pm 20 V, V_{DS} = 0$
C_{iss}	Input Capacitance		900		pF	$V_{DS} = 10 V$
C_{oss}	Output Capacitance		250		pF	$V_{GS} = 0$
C_{rss}	Reverse Transfer Capacitance		45		pF	$f = 1 MHz$
$t_{d(on)}$	Turn-On Delay Time		10		ns	
t_r	Rise Time		40		ns	$I_D = 3 A, V_{CC} \approx 50 V$
$t_{d(off)}$	Turn-Off Delay Time		110		ns	$R_L = 17 \Omega$
t_f	Fall Time		30		ns	$R_{in} = 10 \Omega$

NEC cannot assume any responsibility for any circuits shown or represent that they are free from patent infringement.

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TYPICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)





SWITCHING TIME TEST CIRCUIT

